



**RS1MSWFMQ** 

#### Product Summary (@T<sub>A</sub> = +25°C)

| V <sub>RRM</sub> (V) | I <sub>O</sub> (A) | V <sub>F</sub> Max (V) | I <sub>R</sub> Max (μA) | t <sub>rr</sub> Max (ns) |
|----------------------|--------------------|------------------------|-------------------------|--------------------------|
| 1,000                | 1                  | 1.3                    | 10                      | 500                      |

### **Description and Applications**

The DIODES<sup>™</sup> RS1MSWFMQ is a rectifier packaged in the SOD123F (Type B) package. Providing fast recovery time for high efficiency, this device is ideal for applications such as:

- Reverse protections
- Switching
- Blocking

#### **1.0A SURFACE MOUNT FAST RECOVERY RECTIFIER**

#### **Features and Benefits**

- Glass Passivated Die Construction
- Fast Recovery Time for High Efficiency
- Small Form Factor, Low Profile
- Ideally Suited for Automated Assembly
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The RS1MSWFMQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

#### **Mechanical Data**

- Package: SOD123F
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)

1 0

- Polarity: Cathode Band
- Weight: 0.018 grams (Approximate)



Top View



Bottom View

CATHODE ANODE

Schematic View

0 2

### Ordering Information (Note 4)

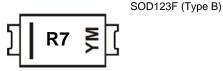
| Part Number   | Package          | Packing |             |  |
|---------------|------------------|---------|-------------|--|
| Fait Nulliper | Гаскауе          | Qty.    | Carrier     |  |
| RS1MSWFMQ-7   | SOD123F (Type B) | 3,000   | Tape & Reel |  |

EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

#### **Marking Information**



R7 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: J = 2022)

M = Month (ex: 8 = August)

Date Code Key

Notes:

| Year  | 2022 | 2023 | 2024 | 2025 | 2026 | 2027 | 2028 | 2029 | 2030 | 2031 | 2032 | 2033 |
|-------|------|------|------|------|------|------|------|------|------|------|------|------|
| Code  | J    | К    | L    | М    | Ν    | 0    | Р    | R    | S    | Т    | U    | V    |
|       | -    |      |      |      |      |      |      |      |      |      |      |      |
| Month | Jan  | Feb  | Mar  | Apr  | Мау  | Jun  | Jul  | Aug  | Sep  | Oct  | Nov  | Dec  |

SOD123F (Type B)



# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

| Characteristic   |                         | Symbol  | Value | Unit |
|--|-------------------------|---|-------|------|
| Peak Repetitive Reverse Voltage<br>Working Peak Reverse Voltage<br>DC Blocking Voltage     |                         | V <sub>RRM</sub><br>V <sub>RWM</sub><br>V <sub>RM</sub> | 1,000 | V    |
| RMS Reverse Voltage  |                         | V <sub>R(RMS)</sub>                                     | 700   | V    |
| Average Rectified Output Current   | @T <sub>A</sub> = +75°C | lo  | 1.0   | А    |
| Non-Repetitive Peak Forward Surge Current<br>8.3ms Single Half Sine-Wave Superimposed on F | ated Load               | I <sub>FSM</sub>  | 25    | А    |

# **Thermal Characteristics**

| Characteristic  | Symbol           | Value       | Unit |
|---|------------------|-------------|------|
| Typical Thermal Resistance, Junction to Case (Note 5) | R <sub>θJC</sub> | 13          | °C/W |
| Thermal Resistance Junction to Ambient (Note 5)       | R <sub>θJA</sub> | 82          | °C/W |
| Operating and Storage Temperature Range               | TJ, TSTG         | -55 to +150 | С    |

#### Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

| Characteristic                     | Symbol             | Min   | Тур         | Max       | Unit | Test Condition  |
|------------------------------------|--------------------|-------|-------------|-----------|------|---|
| Reverse Breakdown Voltage (Note 6) | V <sub>(BR)R</sub> | 1,000 | —           | —         | V    | I <sub>R</sub> = 5μA  |
| Forward Voltage Drop               | VF                 |       | 1.1<br>0.98 | 1.3       | V    | I <sub>F</sub> = 1A, T <sub>J</sub> = +25°C<br>I <sub>F</sub> = 1A, T <sub>J</sub> = +125°C         |
| Leakage Current (Note 6)           | I <sub>R</sub>     |       | 0.3<br>19   | 10<br>200 | μA   | V <sub>R</sub> = 1,000V, T <sub>J</sub> = +25°C<br>V <sub>R</sub> = 1,000V, T <sub>J</sub> = +125°C |
| Reverse Recovery Time              | t <sub>rr</sub>    | —     | 148         | 500       | ns   | $I_F = 0.5A, I_R = 1.0A, I_{rr} = 0.25A$  |
| Total Capacitance                  | CT                 | —     | 4.7         | —         | pF   | $V_R = 4.0V_{DC}$ , f = 1MHz  |

Notes: 5. Device mounted on FR4 PCB with 1x recommended pad layout, 1inch 2oz, as shown on Diodes Incorporated's website at http://www.diodes.com/package-outlines.html.

6. Short duration pulse test used to minimize self-heating effect.



## **RS1MSWFMQ**

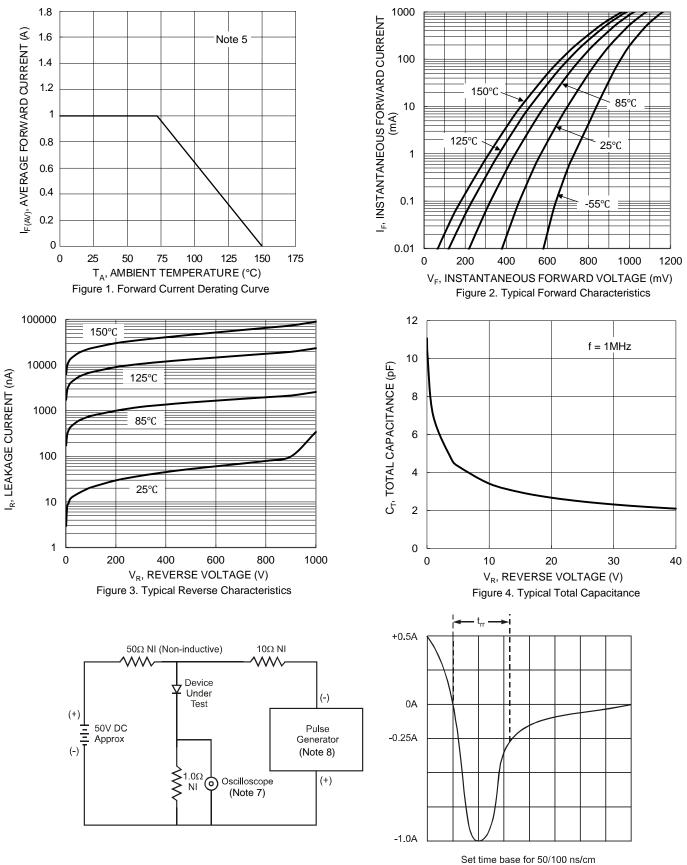


Figure 5. Reverse Recovery Time Characteristic and Test Circuit

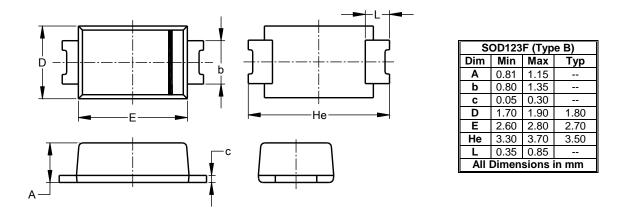
Notes: 7. Rise time = 7.0ns max. Input impedance =  $1.0M\Omega$ , 22pF. 8. Rise time = 10ns max. Input impedance =  $50\Omega$ .



### **Package Outline Dimensions**

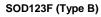
Please see http://www.diodes.com/package-outlines.html for the latest version.

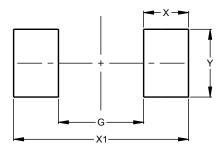
#### SOD123F (Type B)



## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.





| Dimensions | Value<br>(in mm) |
|------------|------------------|
| G          | 1.90             |
| Х          | 1.00             |
| X1         | 3.90             |
| Y          | 1.50             |



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